504475081 07/26/2017 PATENT ASSIGNMENT COVER SHEET

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SUBMISSION TYPE:			NEW ASSIGNMENT		
NATURE OF CONVEYANCE:			ASSIGNMENT		
CONVEYING PARTY	DATA				
			Name	Execution Date	
RUNZI CHANG				05/12/2017	
WINSTON LEE				05/26/2017	
PETER LEE				05/22/2017	
RECEIVING PARTY	ΟΑΤΑ				
Name:	MARVE	ELL S	EMICONDUCTOR, INC.		
Street Address:	5488 M	ARVE	ELL LANE		
City:	SANTA	CLA	RA		
State/Country:	CALIFO	DRNIA	4		
Postal Code:	95054				
		1561			
Property Type			Number		
Application Number:1561		1561	1628		
CORRESPONDENCE					
Fax Number: (408)222-2755					
			e-mail address first; if that is uns		
using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail. Phone: 408-222-2500					
			ng@marvell.com		
			/IN VIVIAN		
		MARVELL LANE			
Address Line 4: SANTA CLARA, CALIFORNIA 95054					
ATTORNEY DOCKET NUMBER:			MP10062		
NAME OF SUBMITTER:			KELVIN VIVIAN		
SIGNATURE:			/Kelvin Vivian/		
DATE SIGNED:			07/26/2017		
Total Attachments: 4					
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ASSIGNMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, each of us, the undersigned,

Runzi Chang Winston Lee Peter Lee

who have created a certain invention for which an application for United States Letters Patent was executed by each of us concurrently herewith and entitled:

INTEGRATED CIRCUIT MANUFACTURING PROCESS FOR ALIGNING THRESHOLD VOLTAGES OF TRANSISTORS

Does hereby sell, assign and transfer to Marvell Semiconductor, Inc., a corporation of California, having a place of business at 5488 Marvell Lane, Santa Clara, CA 95054, its successors, assigns, and legal representatives, the full and exclusive right to said invention and said application and to any and all inventions described in said application for the United States, its territorial possessions and all foreign countries, and the entire right, title and interest in and to any and all Letters Patent which may be granted therefor in the United States, its territorial possessions and all continuations-in-part, continuations, divisions, substitutes, reissues, extensions thereof, and all other applications for Letters Patent relating thereto which have been or shall be filed in the United States, its territorial possessions and/or any foreign countries, and all rights, together with all priority rights, under any of the international conventions, unions, agreements, acts, and treaties, including all future conventions, unions, agreements, acts, and treaties, including all future

Does hereby further sell, assign and transfer to Marvell Semiconductor, Inc., its successors, assigns, and legal representatives, the full and exclusive right to United States Provisional Patent Applications(s) No(s). 62/344,596, filed June 2, 2016, entitled Method to Decouple the FinFET SRAM Transistors Driving Currents Without Changing Process Complexity, and to any and all inventions described in said provisional patent application(s) for the United States, its territorial possessions and all foreign countries, and the entire right, title and interest in and to any and all Letters Patent which may be entitled to the benefit thereof in the United States, its territorial possessions and all continuations-in-part, continuations, divisions, substitutes, reissues, extensions thereof, and all other applications for Letters Patent relating thereto which have been or shall be filed in the United States, its territorial possessions and/or any foreign countries, and all rights, together with all priority rights, under any of the international conventions, unions, agreements, acts, and treaties, including all future conventions, unions, agreements, acts, and treaties, including all future conventions, unions, agreements, acts, and treaties, including all future conventions, unions, agreements, acts, and treaties, including all future conventions, unions, agreements, acts, and treaties, including all future conventions, unions, agreements, acts, and treaties, including all future conventions, unions, agreements, acts, and treaties, including all future conventions.

Agrees that Marvell Semiconductor, Inc., hereinafter referred to as Assignee, may apply for and receive Letters Patent for said invention and said inventions, hereinafter referred to as said invention, in its own name, in the United States, its territorial possessions, and all foreign countries; and that, when requested to carry out in good faith the intent and purpose of this assignment, at the expense of said Assignee, its successors, assigns and legal representatives, the undersigned will execute all continuations-in-part, continuations, divisions, substitutes, reissues, extensions thereof, execute all rightful oaths, assignments, powers of attorney and other papers, testify in any legal or quasi legal proceedings; communicate to said Assignee, its successors, assigns or legal representatives all facts known to the undersigned relating to said invention and the history thereof; and generally do everything possible which said Assignee, its successors, assigns, or legal representatives shall consider desirable for aiding in securing, maintaining and enforcing proper patent protection for said invention and for vesting title to said invention and all applications for patents on said invention in said Assignee, its successors, assigns, or legal representatives; and

Covenants with said Assignee, its successors, assigns, or legal representatives that no assignment, grant, mortgage, license or other agreement affecting the rights and property herein conveyed has been made to others by the undersigned, and that full right to convey the same as herein expressed is possessed by the undersigned.

PATENT REEL: 043104 FRAME: 0184

IN TESTIMONY WHEREOF we have hereunto set our signatures on the date(s) indicated below.

Full Name of First Inventor:	
Runzi Chang	
Inventor's Signature Revendent	Date: Month/Day/Year
/ And the second	5/12/17

	Full Name of Second Inventor:	•	
	Winston Lee		
[Inventor's Signature	Date: Month/Day/Year	
1		 	

Full Name of Third Inventor:	
Peter Lee	
Inventor's Signature	Date: Month/Day/Year

Accepted on behalf of:

MARVELL SEMICONDUCTOR, INC.

al

By:

Kelvin Vivian Director, Intellectual Property

05/30/17

Date:

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IN TESTIMONY WHEREOF we have hereunto set our signatures on the date(s) indicated below.

Runzi Chang Inventor's Signature Date: Month/Day/Year	· · · ·	Full Name of First Inventor:	
X and the second s			
Inventor's Signature Date: Month/Day/Year		Runzi Chang	
		Inventor's Signature	Date: Month/Day/Year
			<i>,</i>

Full Name of Second Inventor:	
Winston Lee	2.
Inventor's Signature	Date: Month/Day/Year
1 Jan Kre	5/26/17
	/ */

Full Name of Third Inventor:		
Peter Lee	. 8 . 1 . 18 ⁶ .	
Inventor's Signature		Date: Month/Day/Year

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Accepted on behalf of:

MARVELL SEMICONDUCTOR, INC.

By:

Kelvin Vivian Director, Intellectual Property

Date:

PATENT REEL: 043104 FRAME: 0186

Page 2/2

IN TESTIMONY WHEREOF we have bereanto set our signatures on the date(s) indicated below.

Rape 2/2

Full Name of First Inventor

Runzi Chang

Inventor's Signature

Date: Month/Day/Year

Full Name of Second Inventor:

Winston Lee Inventor's Signature

Date: Month/Day/Vear

Full Name of Third Inventor:

Peter Lee Inventor's 2

Inventor's Signature $\mathbb{Z}^{\mathcal{O}}$ ę

Date: Month/Day/Year 122/2017

Accepted on behalf of:

MARVELL SEMICONDUCTOR, INC.

By:

Kelvin Vivian Director, Intellectual Property

Date: